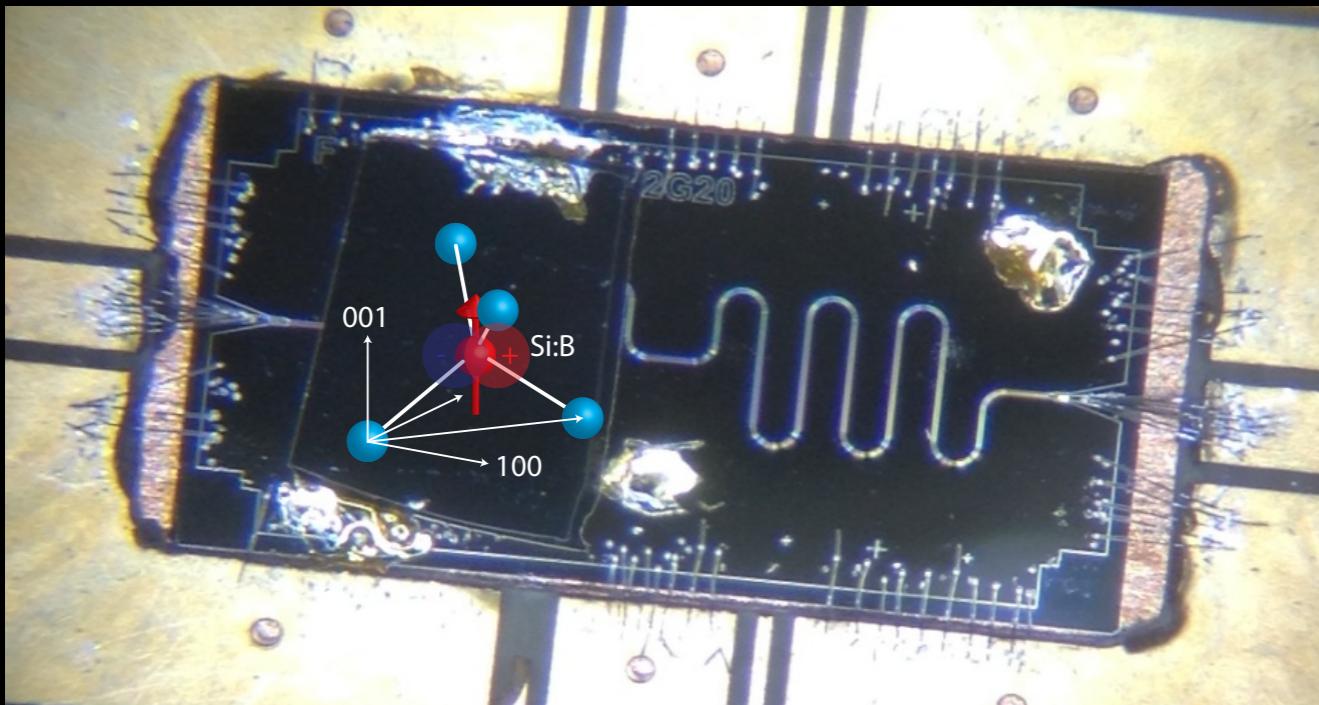


Ultra-long coherence times of spin-orbit qubits



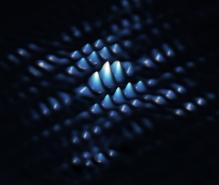
J. Salfi
Asst. Prof.

Dept of Electrical and Computer Eng.
The University of British Columbia

Quantum Information: Quo Vadis?

November 13, 2019

Kobayashi, **Salfi**, van der Heijden, Chua, Culcer, House, Johnson, McCallum, Riemann, Abrosimov, Becker, Pohl, Simmons, Rogge, arxiv:1809.10859.



Quantum Computing

Aim: Scalable system of atom-based qubits [this talk]

Long coherence times 

High fidelity single-qubit operations 

High fidelity long-distance deterministic multi-qubit operations

Frontiers: Building large systems with above properties

Hybrid quantum systems

Aim: Problem-specific success with quantum simulators [a different talk]

Special purpose problems to address

.. Ideally that are hard for trapped ion and superconducting qubits

Fermions [1,2] are hard to simulate using most systems

[1] Salfi et al, Nature Comms 2016

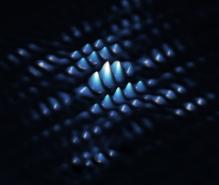
[2] Hensgens et al, Nature 2017



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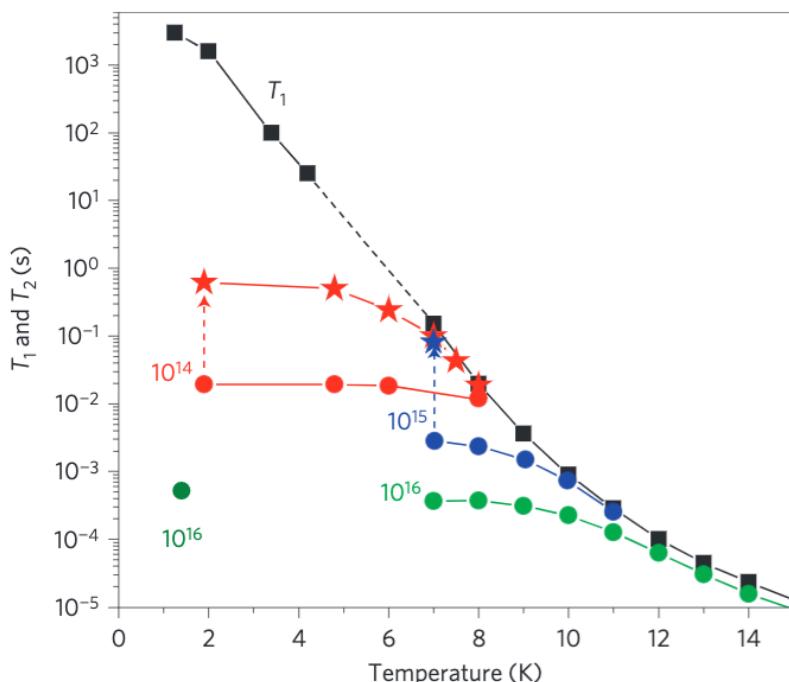
Electron Spin Qubits in Silicon

What is special about ^{28}Si ?

Solid-state system with among the longest coherence times available

Donor ensembles

$T_2 \sim 10 \text{ ms plus}$



Tyryshkin et al,
Nature Mat, 2011



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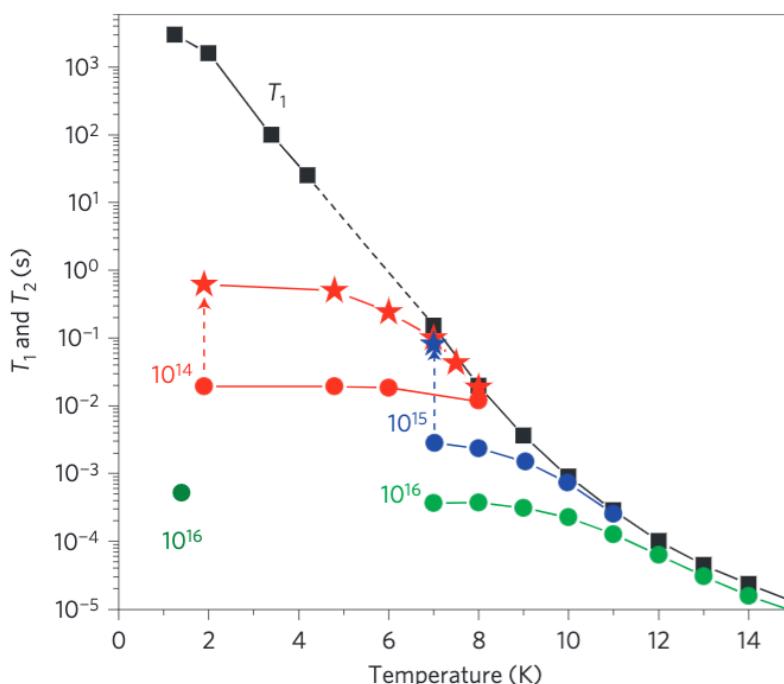
Electron Spin Qubits in Silicon

What is special about 28Si?

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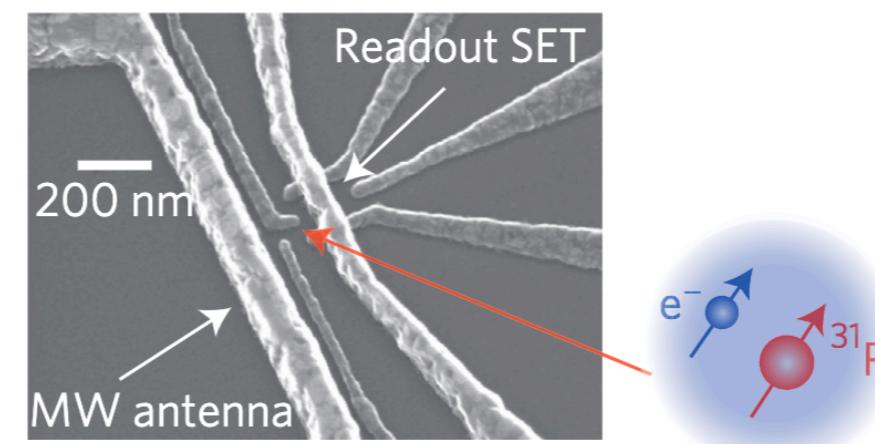
$T_2 \sim 10 \text{ ms plus}$



Tyryshkin et al,
Nature Mat, 2011

Single donor

$T_2 \sim 100 \text{ ms}$



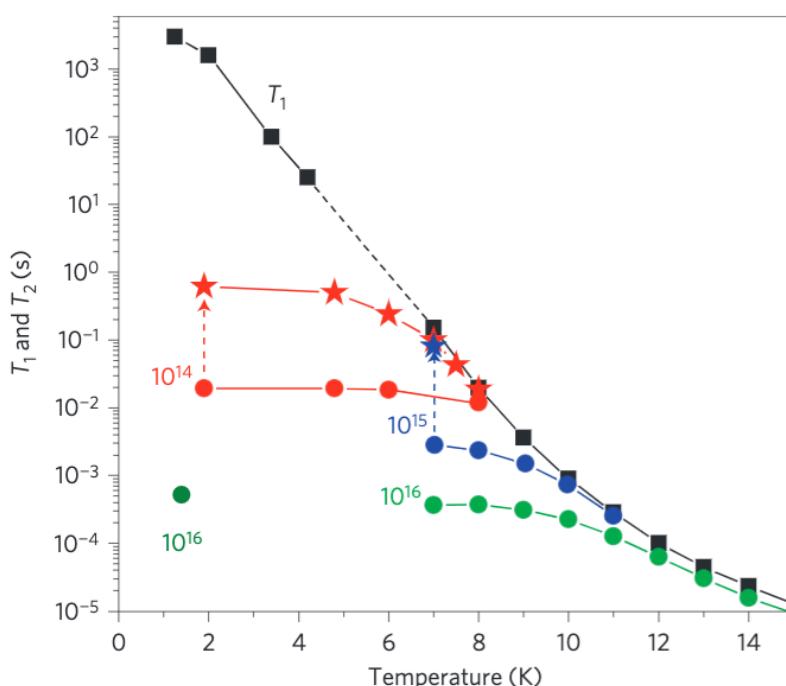
Muhonen et al,
Nature Nano, 2014

Electron Spin Qubits in Silicon

What is special about 28Si?

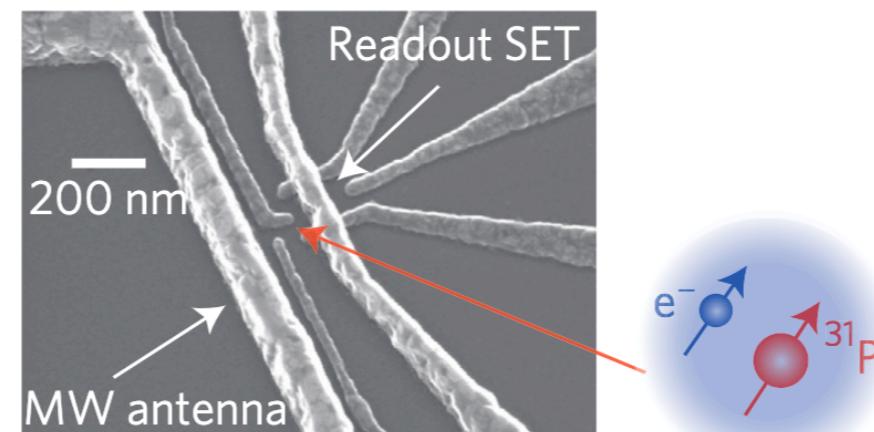
Solid-state system with among the longest coherence times available

Donor ensembles
 $T_2 \sim 10$ ms plus



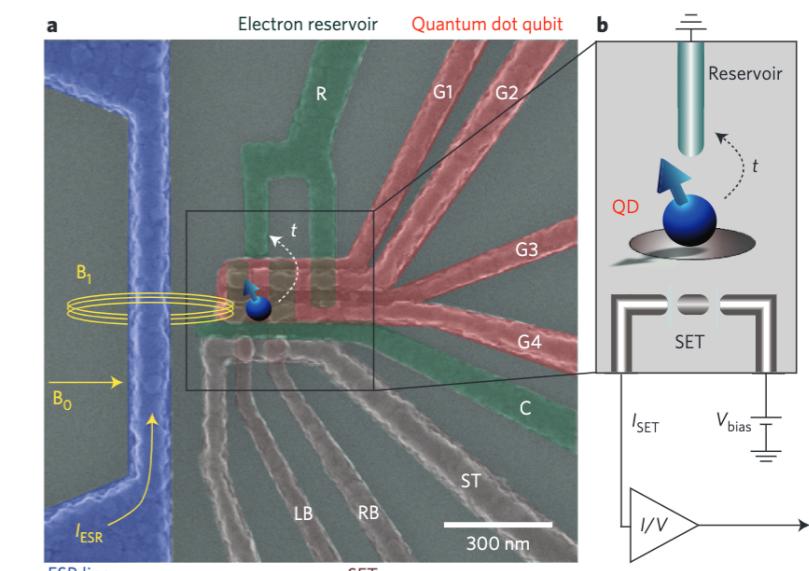
Tyryshkin et al,
Nature Mat, 2011

Single donor
 $T_2 \sim 100$ ms



Muhonen et al,
Nature Nano, 2014

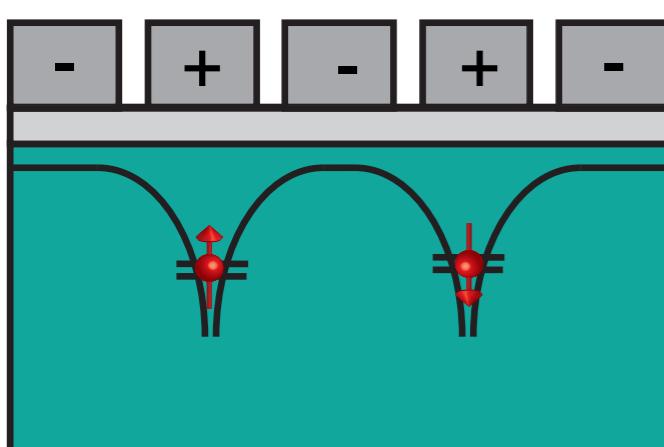
Single quantum dot
 $T_2 \sim 30$ ms



Veldhorst et al,
Nature Nano, 2014

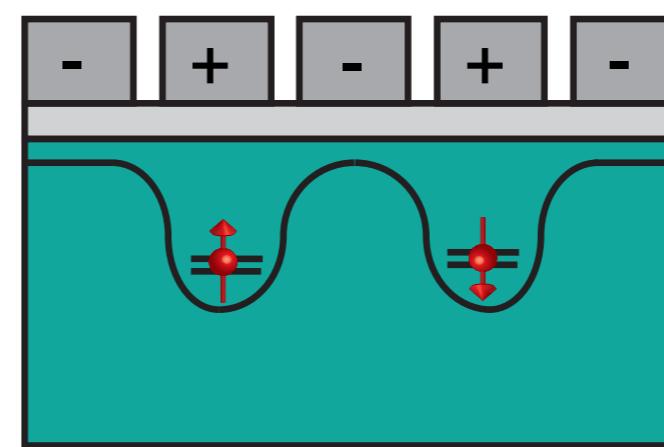
Electron Spin Qubits in Silicon

Donors $T_2 \sim 100$ ms



Muhonen et al Nature 2014

Quantum dots $T_2 \sim 30$ ms



Gates
 SiO_2
Si

Veldhorst et al Nature Nano 2014

Donor qubit measurement (spin to charge conversion)

Watson et al, Science Advances, 2016

$$p_e = 2 \times 10^{-3}$$

High accuracy single qubit gates (magnetic resonance)

Dehollain et al NJP 2016

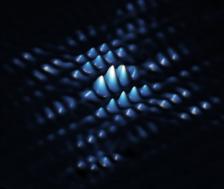
$$p_e = 5 \times 10^{-4}$$

Two-qubit gates (exchange interaction)

Huang et al Nature 2019

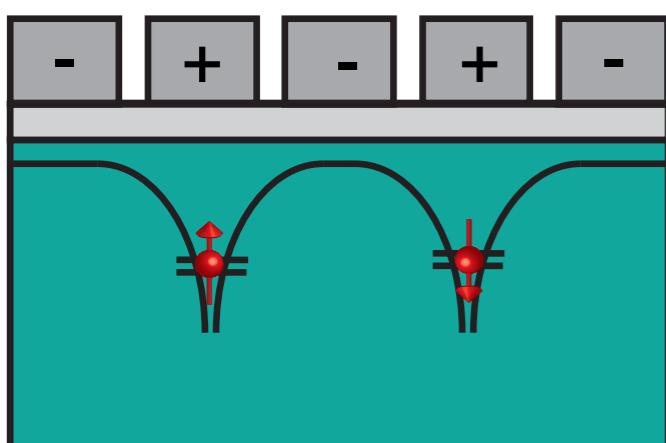
$$p_e \sim 4 \times 10^{-2}$$

Challenges: short-range interactions: electric noise, circuit density



Electron Spin Qubits in Silicon

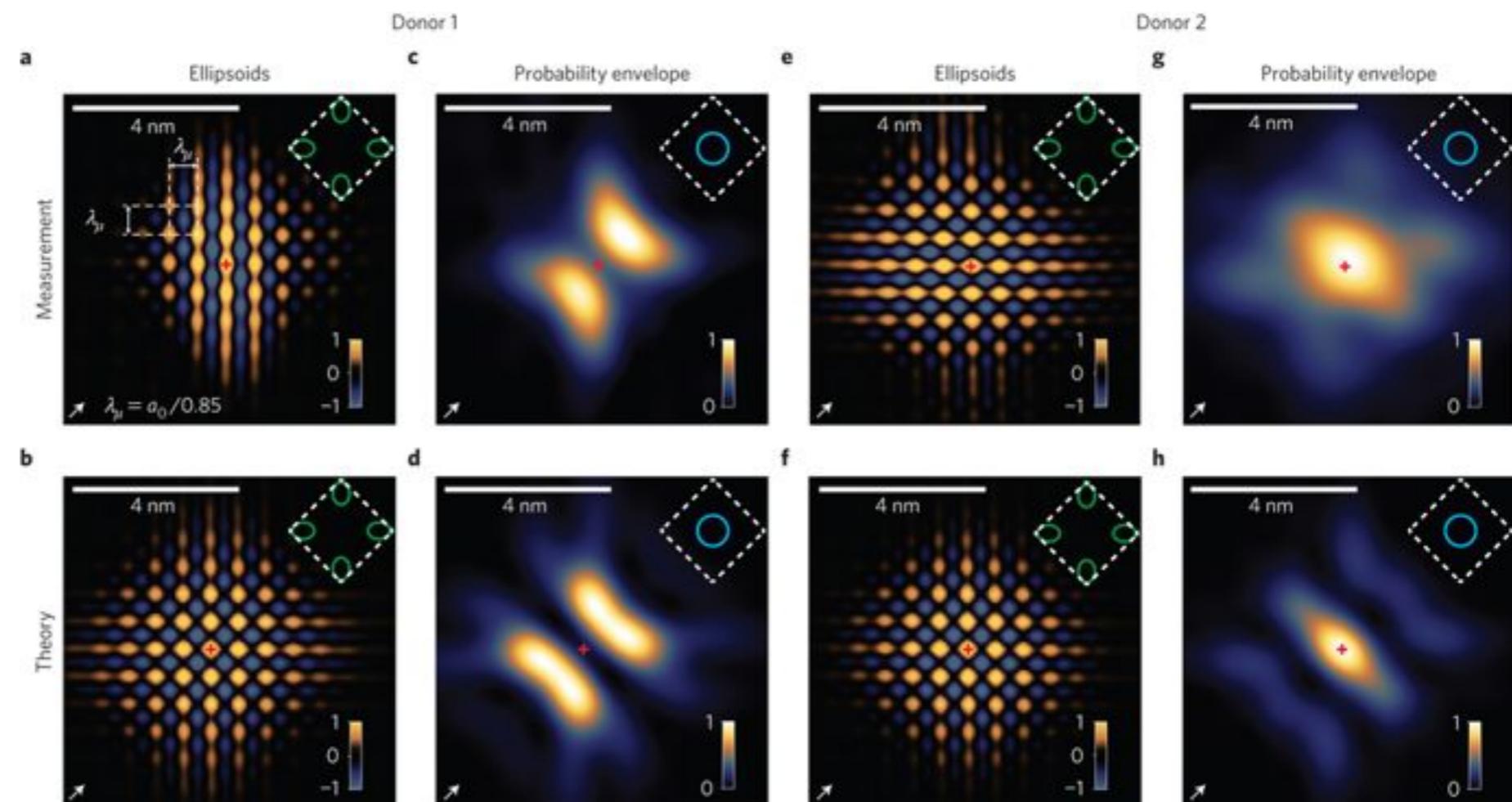
Donors $T_2 \sim 100$ ms



Muhonen et al Nature 2014

Gates
 SiO_2
Si

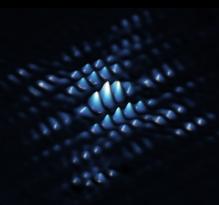
Direct quantum state measurements
Salfi Nature Materials 2014



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Scalability

Objective

Coherence of atomic qubits in ^{28}Si

Long-range noise-insensitive interconnects

1. Quantum electrodynamics (microwave photons)
2. Acoustic phonons
3. Capacitive interactions

How to accomplish this?

Activate the electric dipole for spin

Maintain qubit coherence

Why is this hard in Silicon?

Si electron spin has weak intrinsic coupling to electric fields

Mechanisms to engineer coupling this usually lead to decoherence



Electric Control

Intrinsic electric dipole: Electric field $E(t)$ moves electron, and it experiences time-varying $B(t)$ [special relativity] Thomas, Nature 1926

Strong spin decoherence [1-6] $T_2 \sim 0.1$ to $1 \mu\text{s}$

For electrons in Si, the effect is far too weak

[1] Nowack et al Science 2007

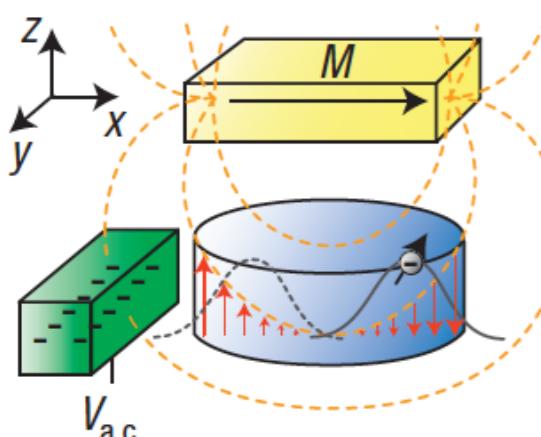
[2] Nadj-Perge et al Nature 2010

[3] Maurand Nature Comm 2016

[4] Watsinger Nature Comm 2018

[6] Hendrickx, arxiv:1904.11443

Artificial electric dipole? $E(t)$ moves electron $x(t), B(x(t))$ from magnet



First demonstrated in GaAs [7]

Suppressed coherence for Si [9,10]

$T_2 \sim 1 \mu\text{s}$

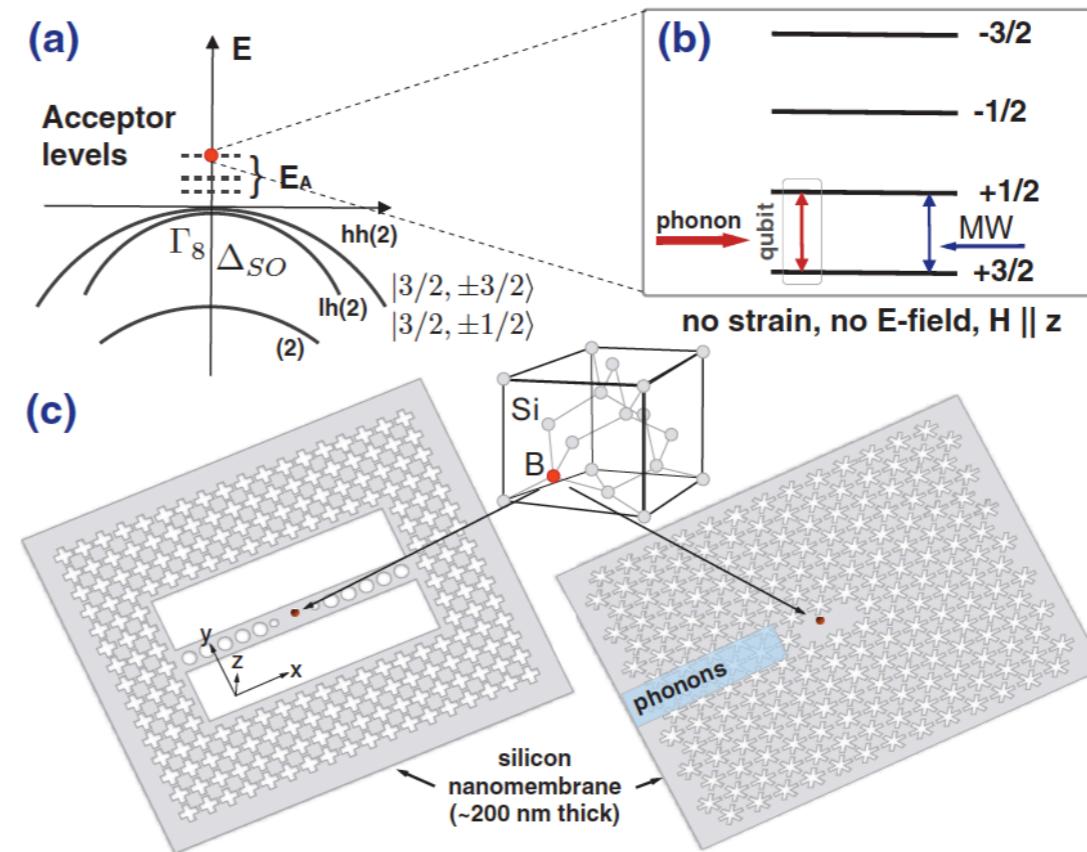
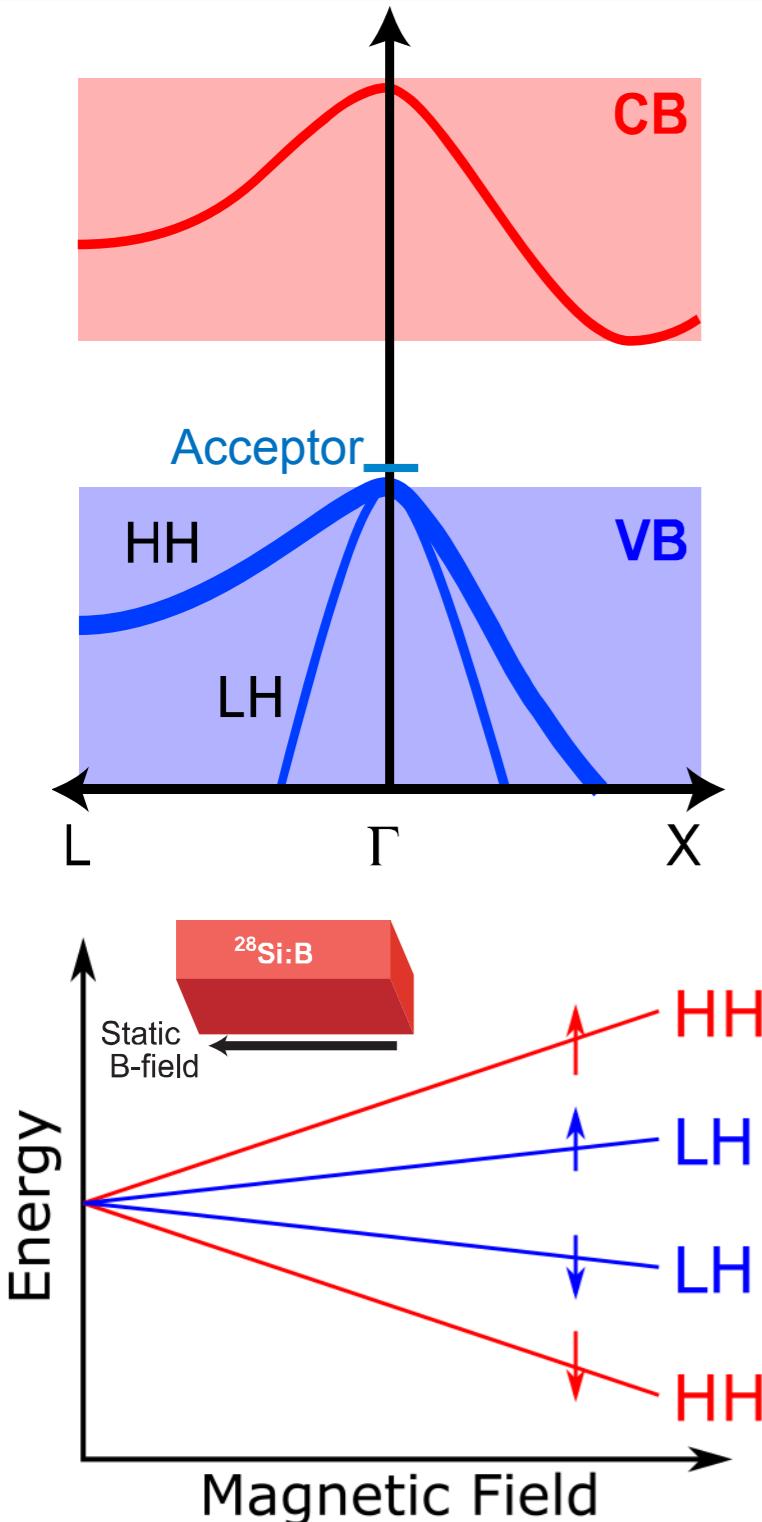
[7] Pioro-Ladrière et al Nature Physics 2008

[8] Kawakami et al Nature Nanotech 2014

[9] Mi et al Nature 2018

[10] Samkharadze et al Science 2018

Si:B acceptors



Long-ranged interactions
2Qbit gate with phonons
Long relaxation times

Ruskov PRB 2013

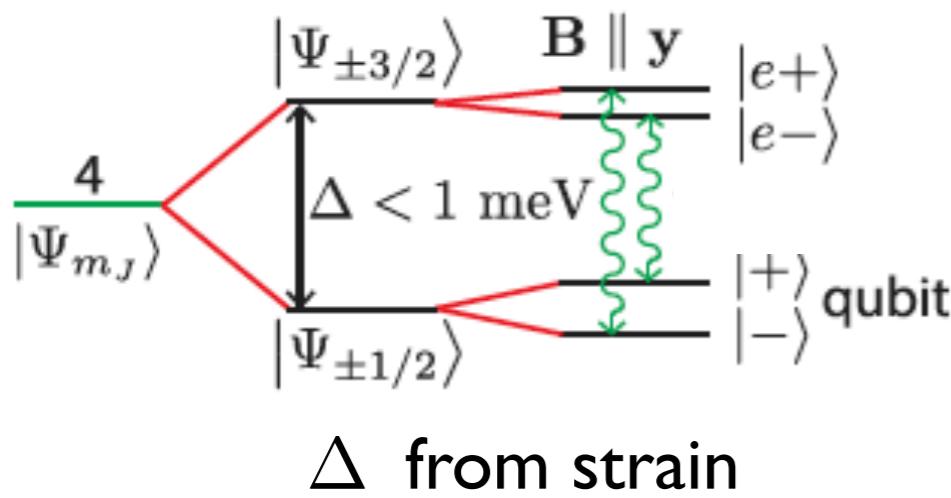
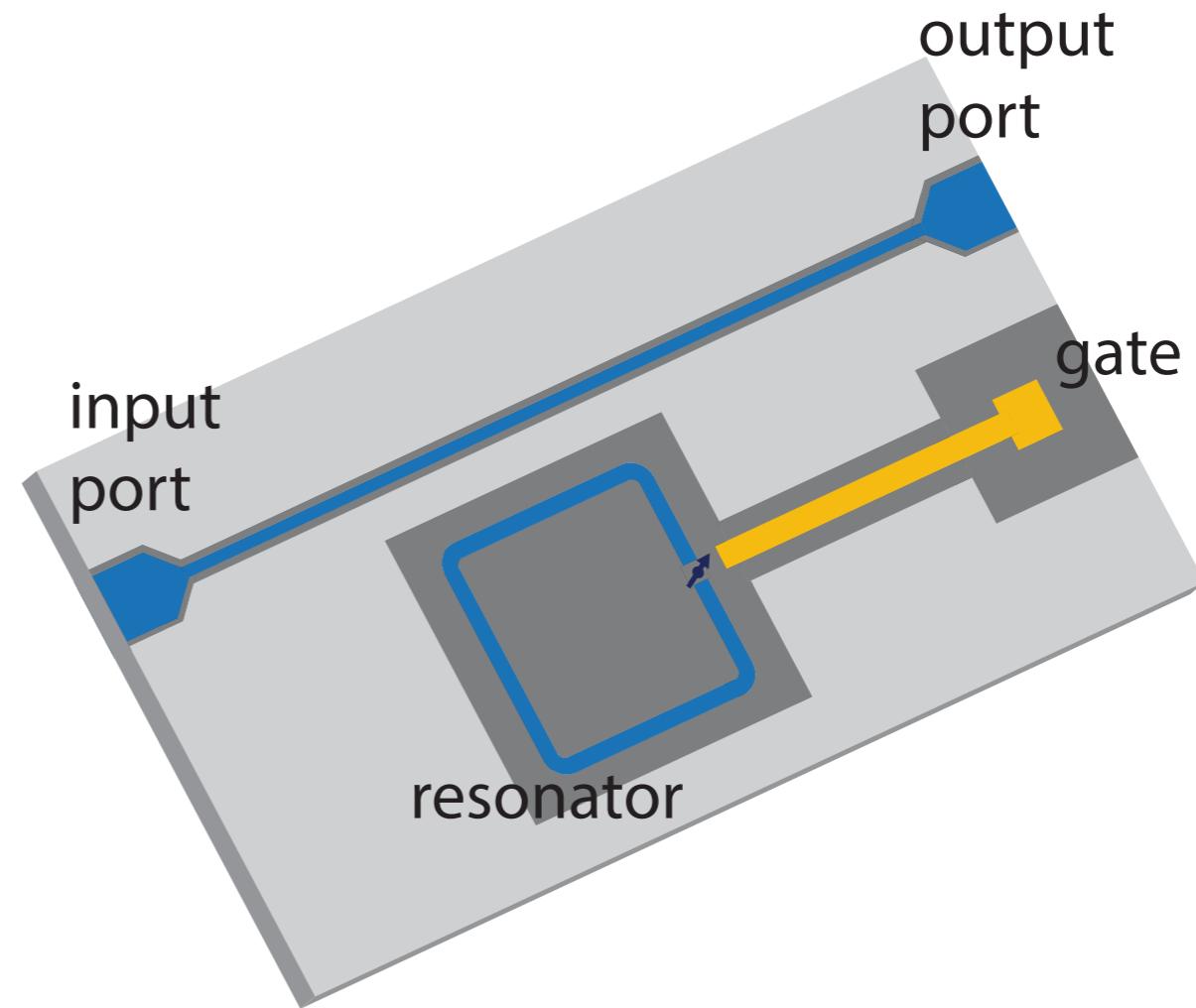
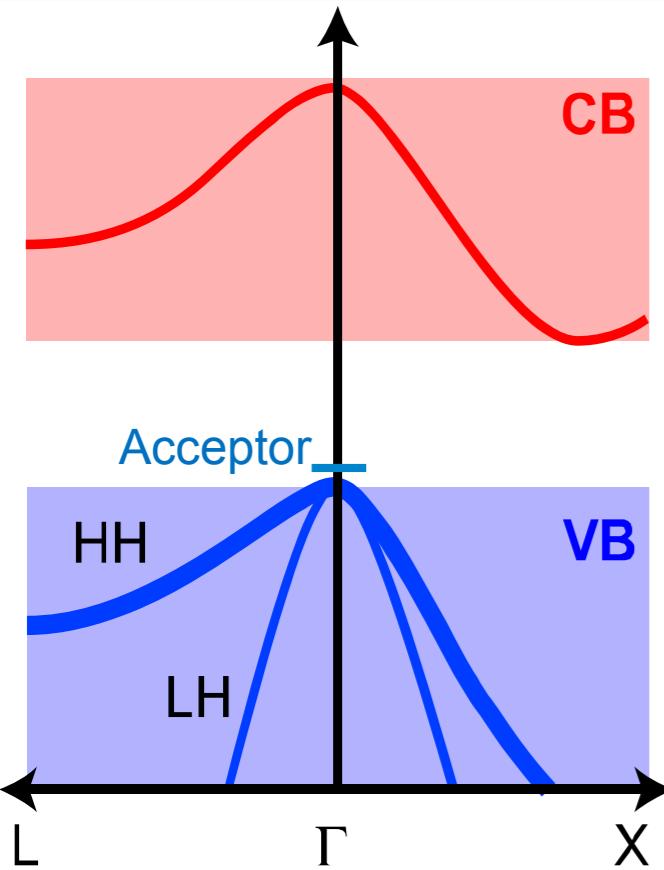


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Si:B acceptors



Long-ranged interactions
2Qbit gate with microwave photons
Long coherence times

Salfi, Mol, Culcer, Rogge PRL 2016

Salfi, in IOP Quantum Nanotechnology Roadmap (2019, submitted)



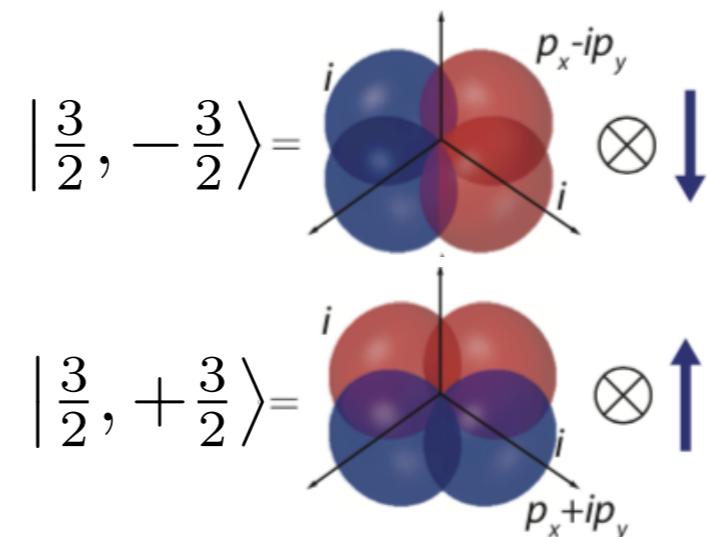
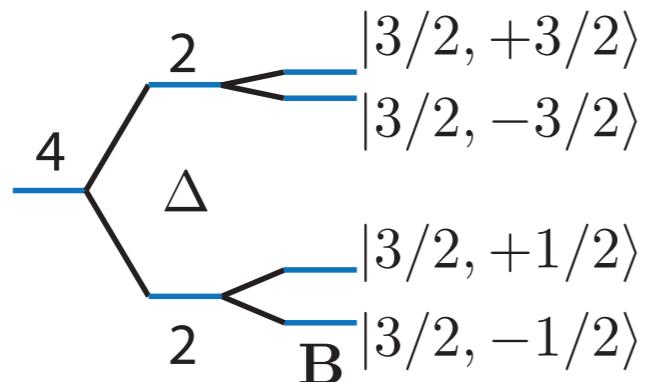
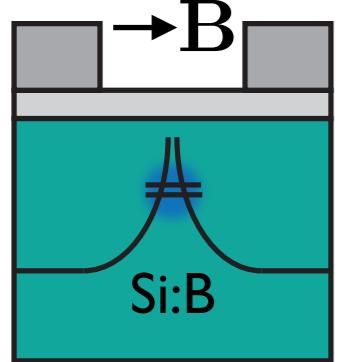
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Si:B acceptors

Si valence holes, $J=3/2$



L.S



HH

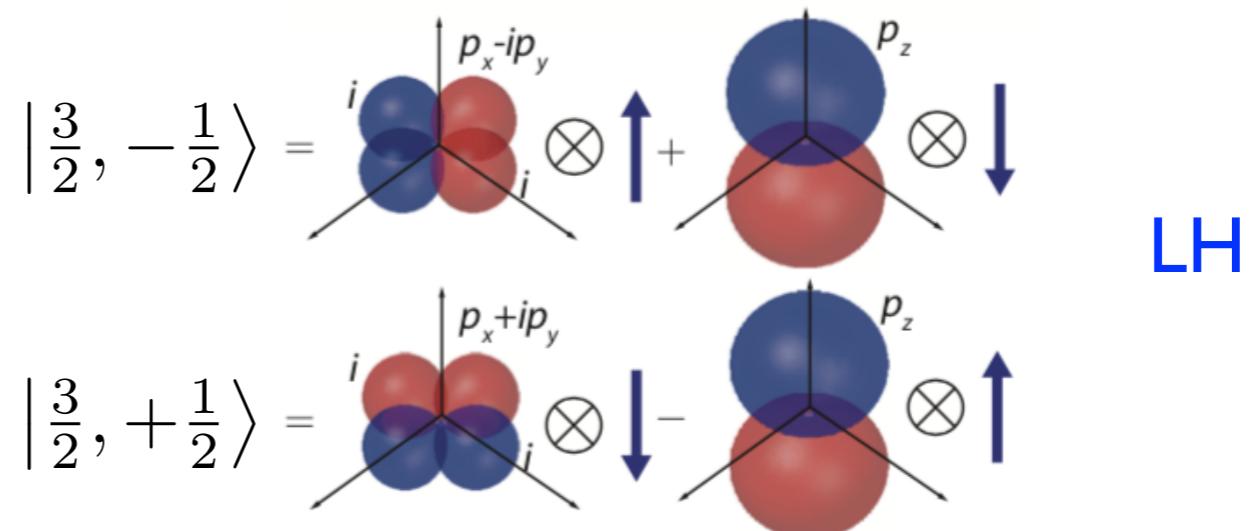
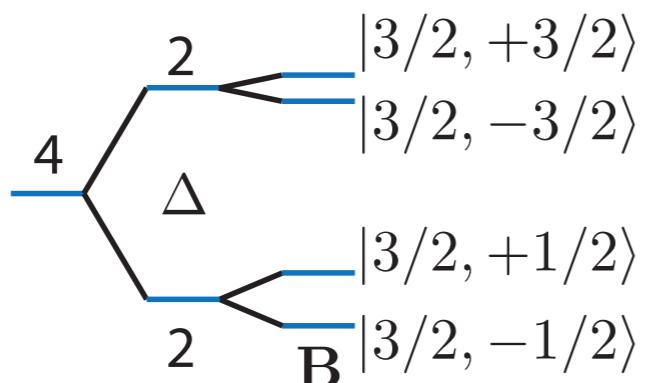
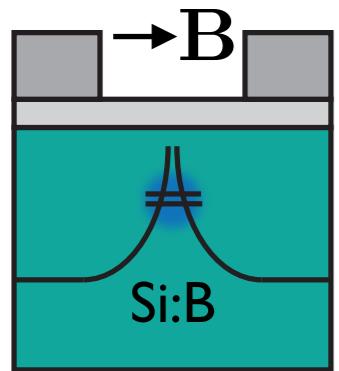
Spin-3/2 system in silicon, with electric quadrupole

Si:B acceptors

Si valence holes, $J=3/2$



L.S



LH

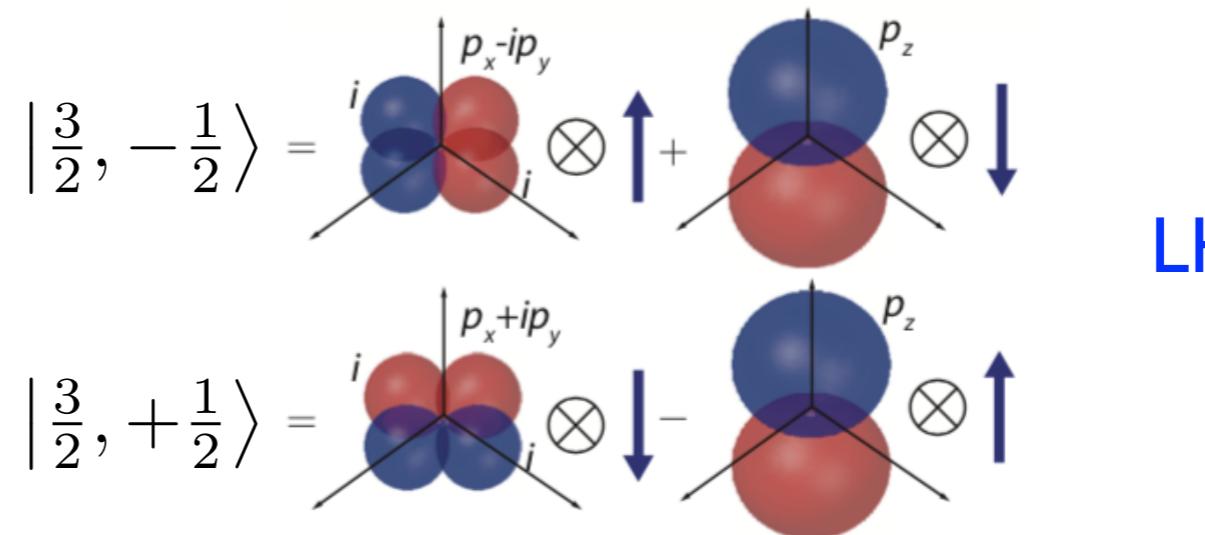
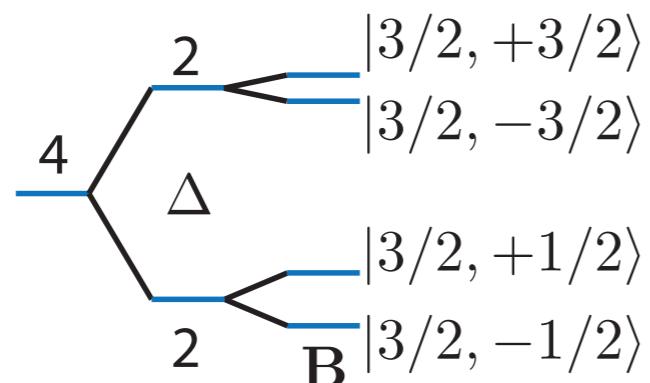
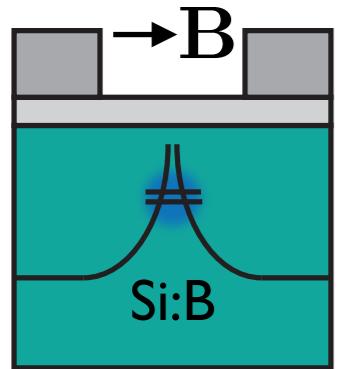
Spin-3/2 system in silicon, with electric quadrupole

Si:B acceptors

Si valence holes, $J=3/2$



L.S



LH

Spin-3/2 system in silicon, with electric quadrupole

Our findings

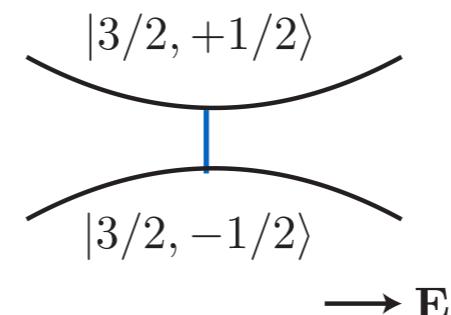
1-qubit, 2-qubit gates:

Strong electric dipole coupling

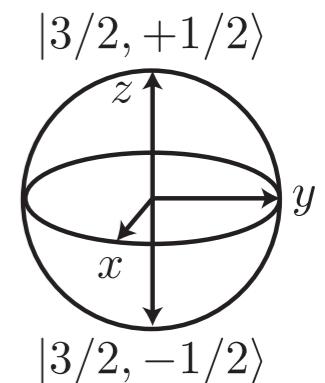
Coherence:

Robust to E field noise

Salfi et al PRL 2016



electric clock transition!!



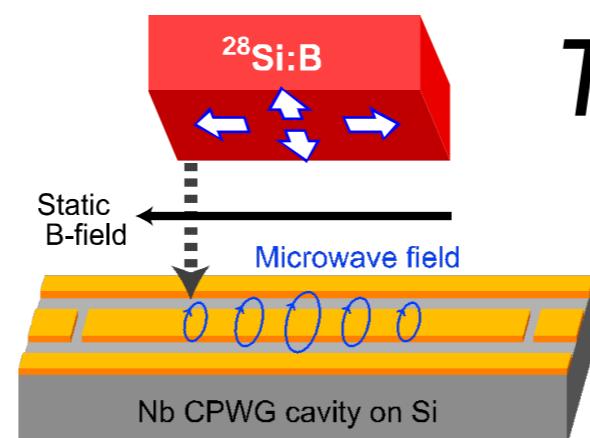
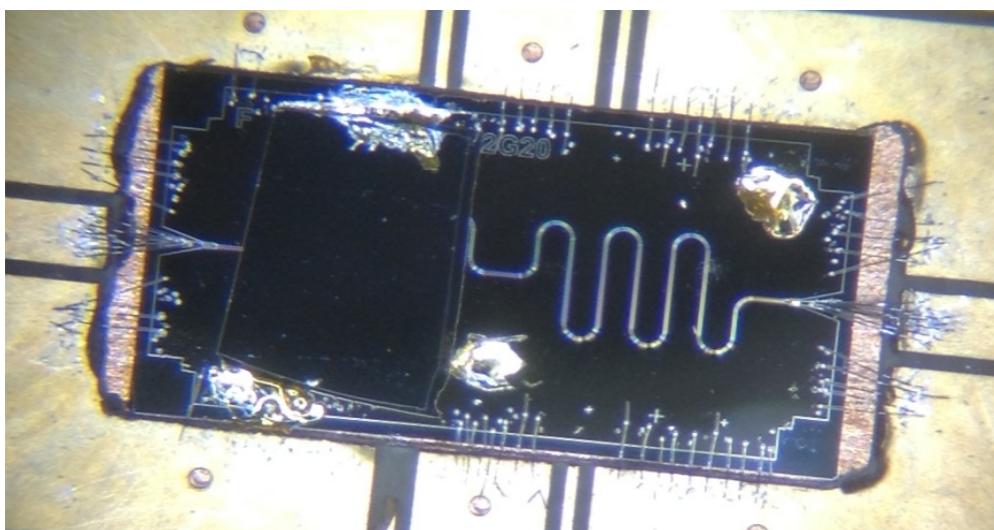
Hole spin coherence

Objective: Investigate and engineer hole spin coherence in Si:B atoms
 ^{28}Si , strain to engineer coherence and relaxation

Methodology: Planar superconducting resonator

Technology to couple/measure/control superconducting qubits

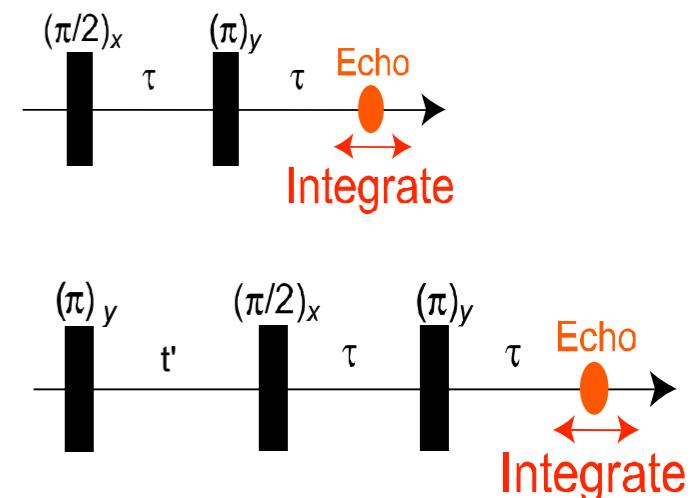
We use NbN rather than Aluminum (tolerates **B** field)



$T_{2\text{Hahn}}$

T_1

$T_{2\text{CPMG}}$



Kobayashi, **Salfi** et al, arxiv:1809.10859

Hole spin coherence

Superposition preparation

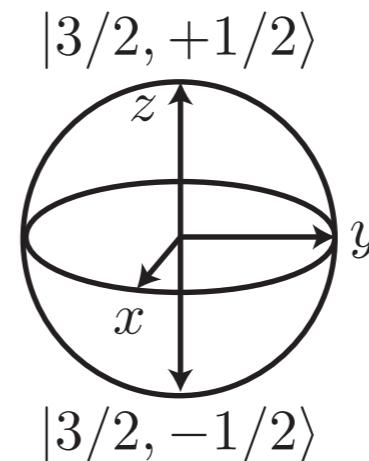
Apply $X(\pi/2)$ pulse (input)

Refocusing

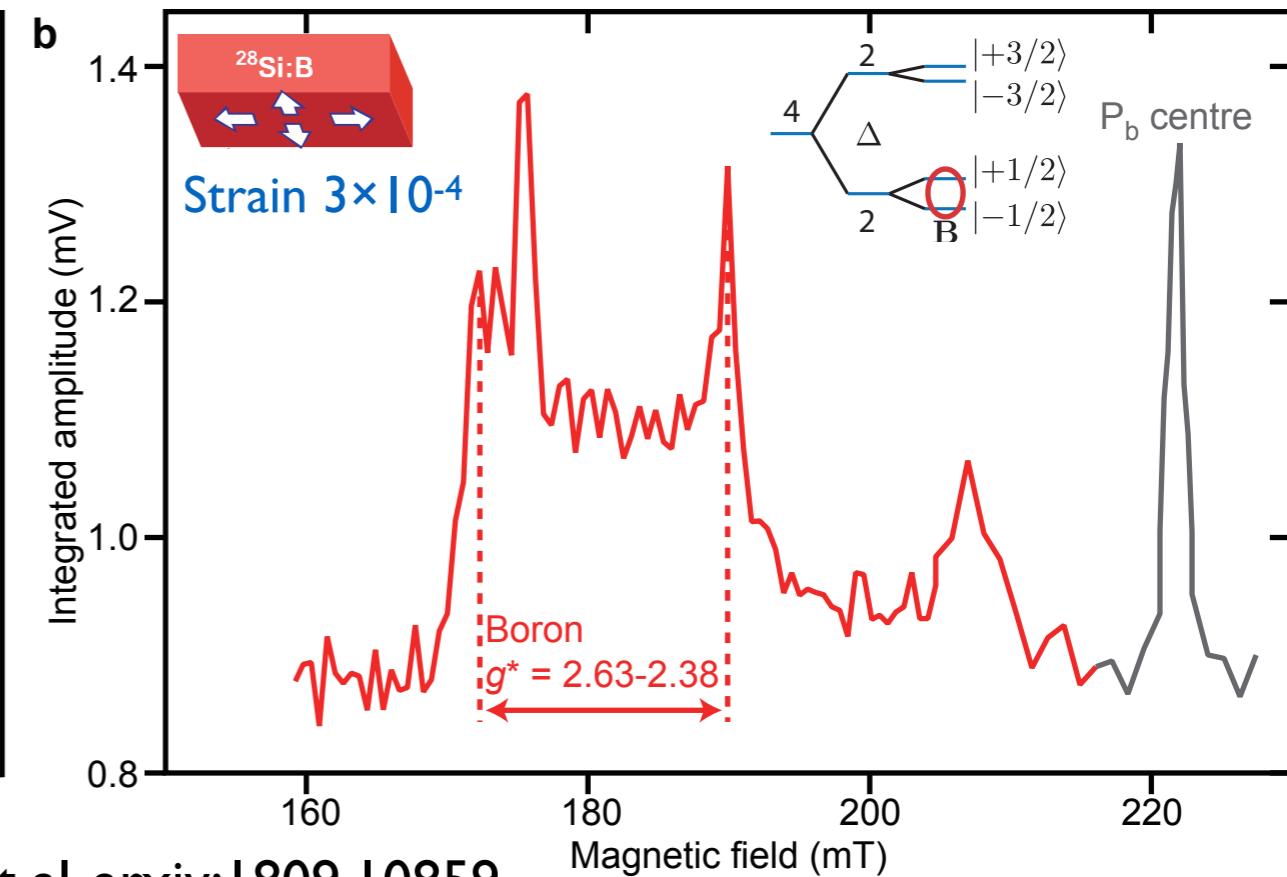
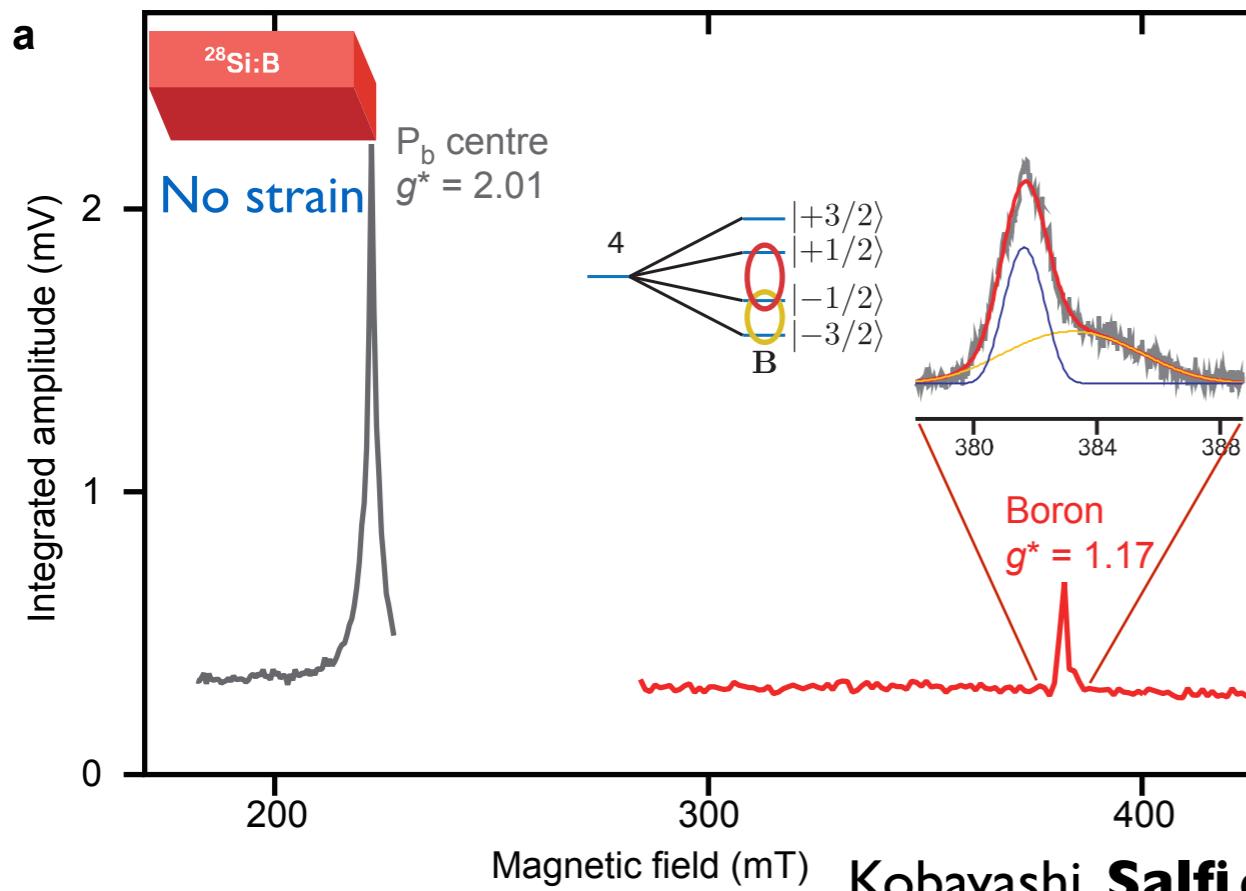
After time t , apply $X(\pi)$ pulse

Measurement

After time $2t$, refocusing occurs, photons can be emitted into cavity

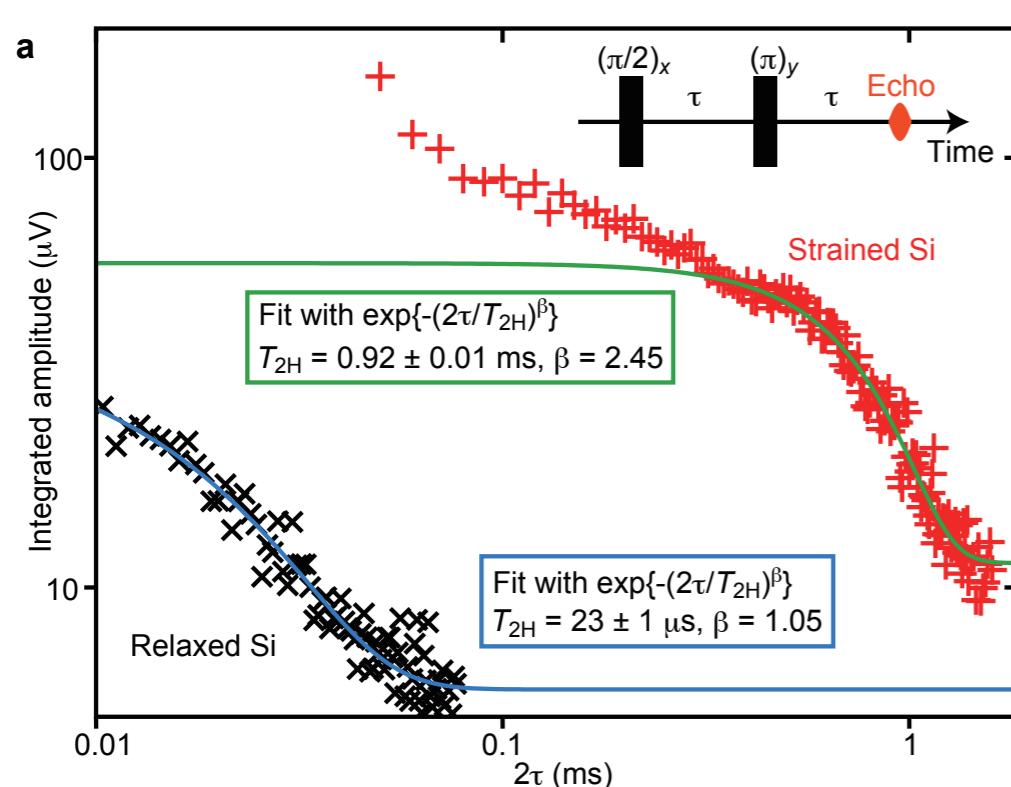


$$hf = g^* \mu_B B$$
$$f = 6.6 \text{ GHz}$$



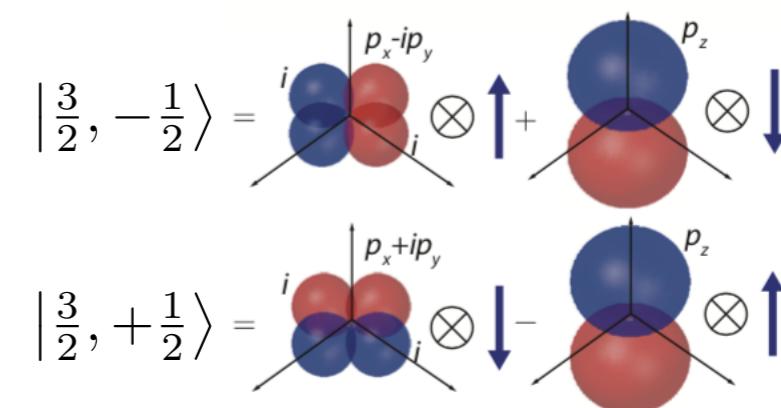
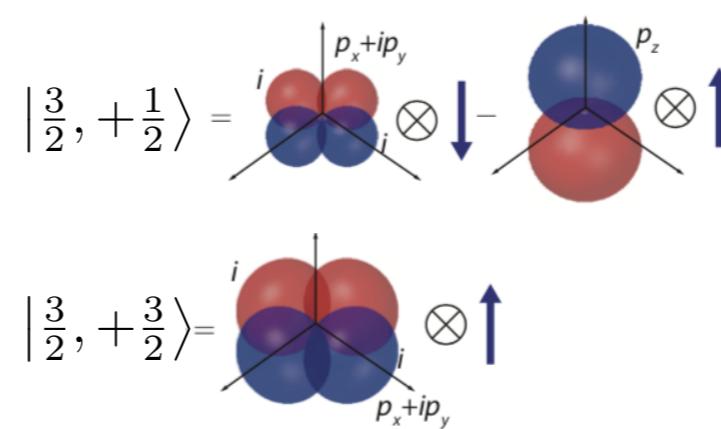
Kobayashi, Salfi et al, arxiv:1809.10859

Hole spin coherence



Unstrained sample:
 $T_2=23 \text{ } \mu\text{s}, \beta=1.05$

Strained sample:
 $T_2=0.9 \text{ ms}, \beta=2.45$



Strained sample with $m_j=1/2$ eigenstates and $J=3/2$ has longer lifetime
These states are time-reversal symmetric

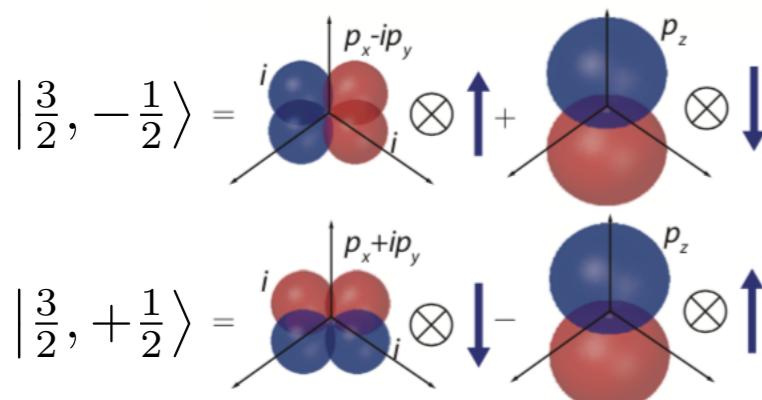
Change in β from ~ 1 to > 2 ?
 τ_c =correlation time of the fluctuator is changing

Kobayashi, **Salfi** et al, arxiv:1809.10859

Hole spin coherence

Strained sample:

$T_2=0.9$ ms, $\beta=2.45$

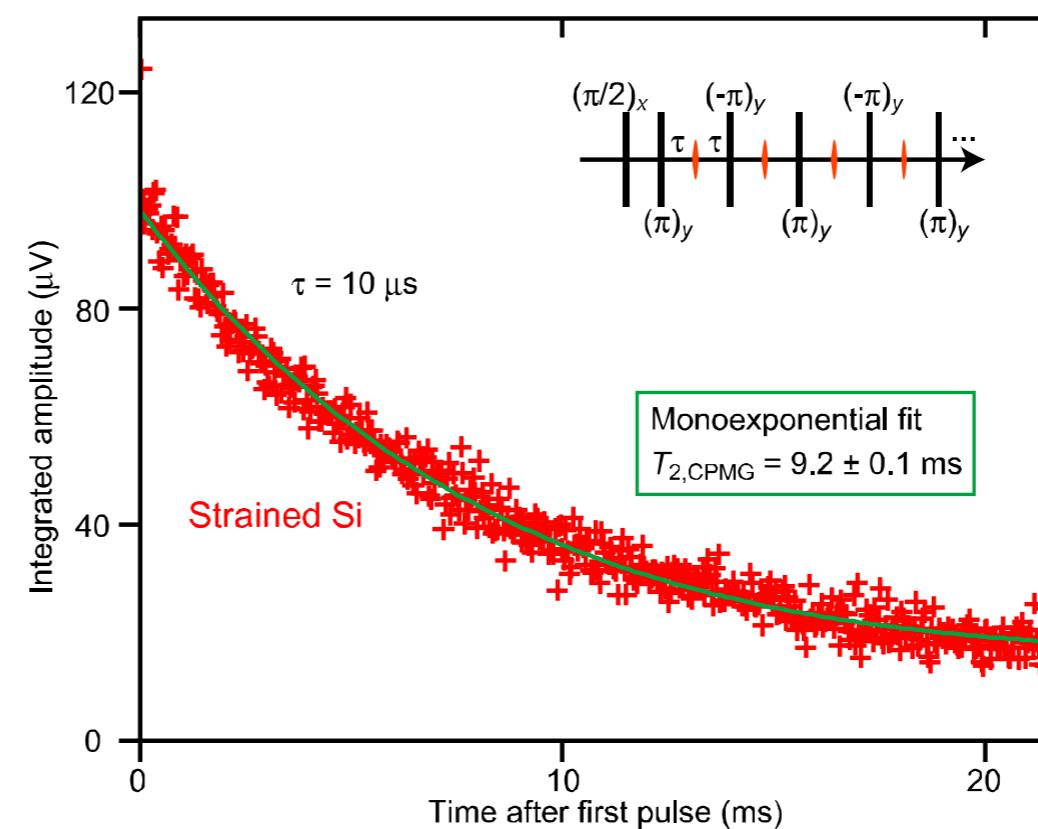


Exponent $\beta=2.45$

Spectral diffusion

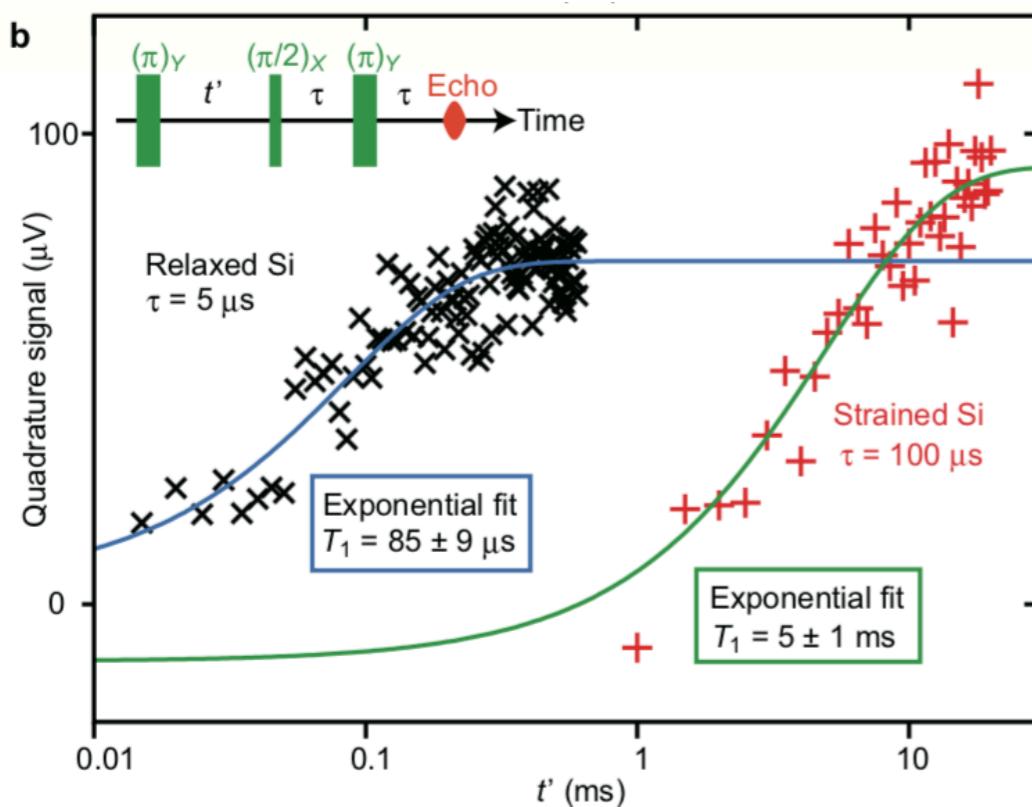
Dynamical decoupling

$T_{2,\text{CPMG}} = 9.2$ ms



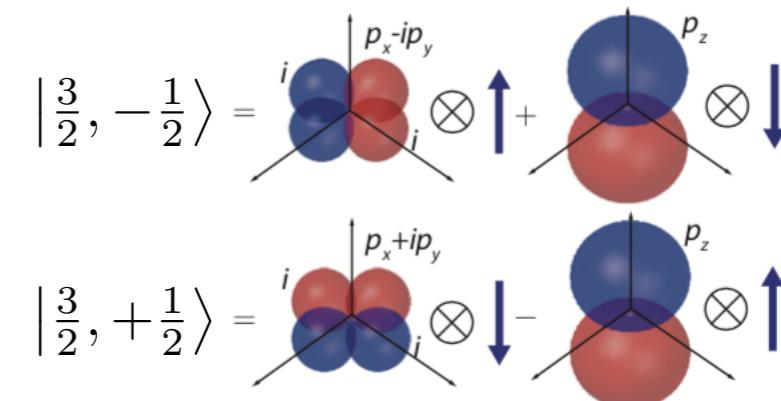
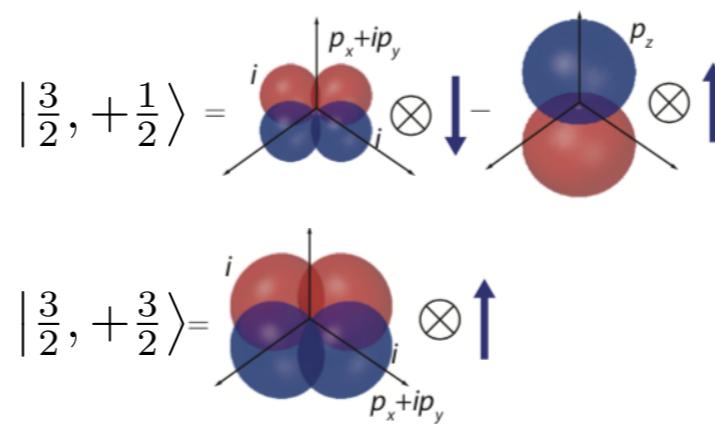
Kobayashi, **Salfi** et al, arxiv:1809.10859

Hole spin coherence



Unstrained sample:
 $T_1=85 \mu\text{s}$

Strained sample:
 $T_1=5 \text{ ms}$



Strained sample with $m_J=1/2$ eigenstates and $J=3/2$ has longer T_1
Reduced spin-phonon coupling

10 ms $T_{2\text{CPMG}}$ is a close to T_1 -limited spin coherence time
 T_1 reasonably long but can be increased further

Kobayashi, **Salfi** et al, arxiv:1809.10859

Comparison to state-of-the-art

this work

System	T_2H	T_2CPMG
Si:P e- [1]	4 ms	-
Si:P e- [2]	0.95 ms	~ 100 ms
Si e- QD [3]	1.2 ms	~ 28 ms
Si h+ QD [4]	$0.25 \mu s$	-
Si:B h+ no strain	$23 \mu s$	-
Si:B h+ strain	0.9 ms	9 ms

~ 100 ms T_2 of electrons
no electric dipole

- [1] Tyryshkin Nature Mat 2011
- [2] Muhonen Nature Nanotech 2013
- [3] Veldhorst Nature Nanotech 2014
- [4] Maurand Nature Comms 2016

Kobayashi, **Salfi** et al, arxiv:1809.10859



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Comparison to state-of-the-art

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Si h+ QD [4]	$0.25 \mu s$	-
Si:B h+ no strain	$23 \mu s$	-
Si:B h+ strain	0.9 ms	9 ms

$\sim 0.25 \mu s T_2$ of hole QD
with electric dipole

- [1] Tyryshkin Nature Mat 2011
- [2] Muhonen Nature Nanotech 2013
- [3] Veldhorst Nature Nanotech 2014
- [4] Maurand Nature Comms 2016

Kobayashi, **Salfi** et al, arxiv:1809.10859



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Comparison to state-of-the-art

System	T_2H	T_{2CPMG}
Si:P e- [1]	4 ms	-
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Si h+ QD [4]	0.25 μ s	-
Si:B h+ no strain	23 μ s	-
Si:B h+ strain	0.9 ms	9 ms

Si:B holes
~ 1 ms T_2
~ 10 ms T_{2CPMG}
with electric dipole

this work

- [1] Tyryshkin Nature Mat 2011
- [2] Muhonen Nature Nanotech 2013
- [3] Veldhorst Nature Nanotech 2014
- [4] Maurand Nature Comms 2016

Intrinsic electric dipoles are compatible with long coherence times
 10^4 to 10^5 times improvement over previous spin-orbit systems

Kobayashi, **Salfi** et al, arxiv:1809.10859



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Hole spin coherence

How does the strain improve coherence? $\mathcal{H} = \left(\hbar\omega + \frac{d\hbar\omega}{\delta E_z} \delta E_z \right) \sigma_z + \nu E_x \sigma_x$

Decoherence is suppressed by the gap

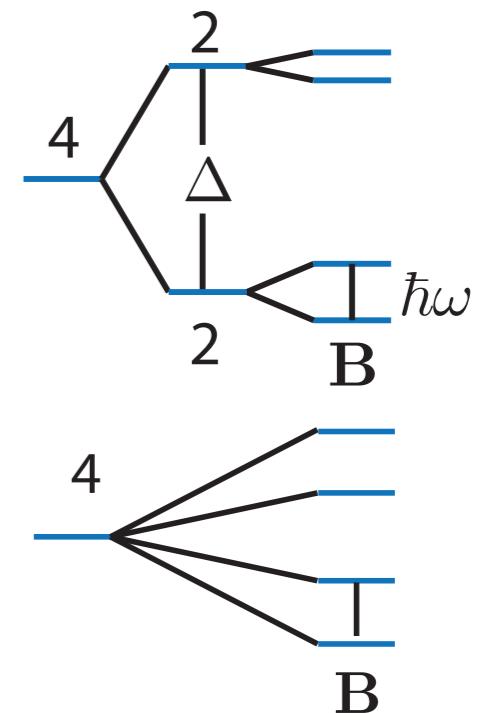


$$\frac{\delta\hbar\omega}{\delta E_z} = \boxed{\frac{\hbar\omega}{2\Delta}} \sin(2\theta) \sqrt{3}p$$

for small $\frac{\hbar\omega}{\Delta}$



$$\text{c.f. } \frac{\hbar\delta\omega}{\delta E_z} = \sin(2\theta) \sqrt{3}p \quad \text{for big } \frac{\hbar\omega}{\Delta}$$



Experiment: Reduced longitudinal coupling enhances T_2

- [1] Decoherence from electric fluctuations
- [2] Decoherence from electric dipole-dipole interaction

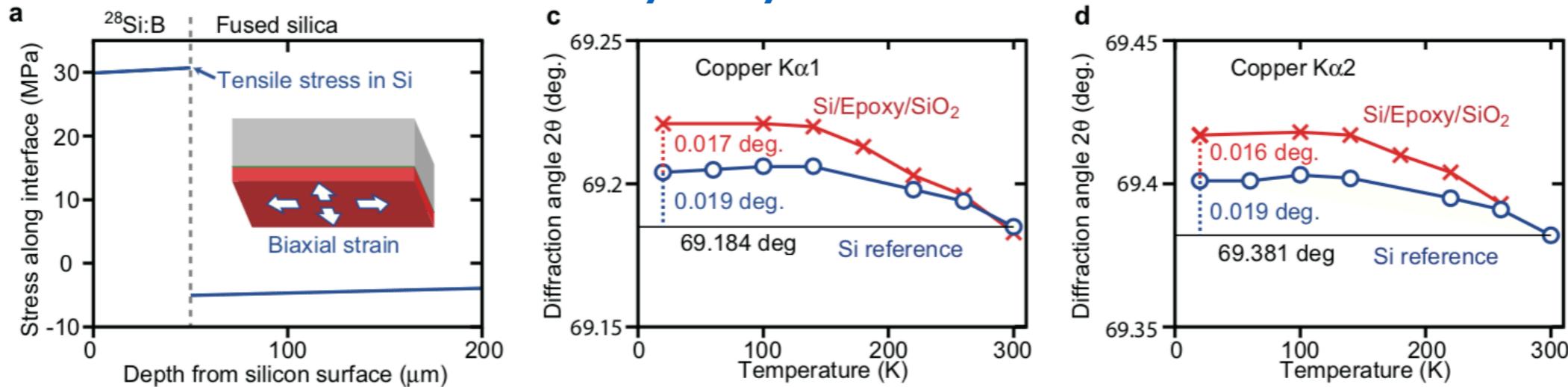
Conveniently, T_1 is a good measure of the strain-induced gap

$$\frac{\hbar\omega}{\Delta} \sim \frac{1}{5}$$

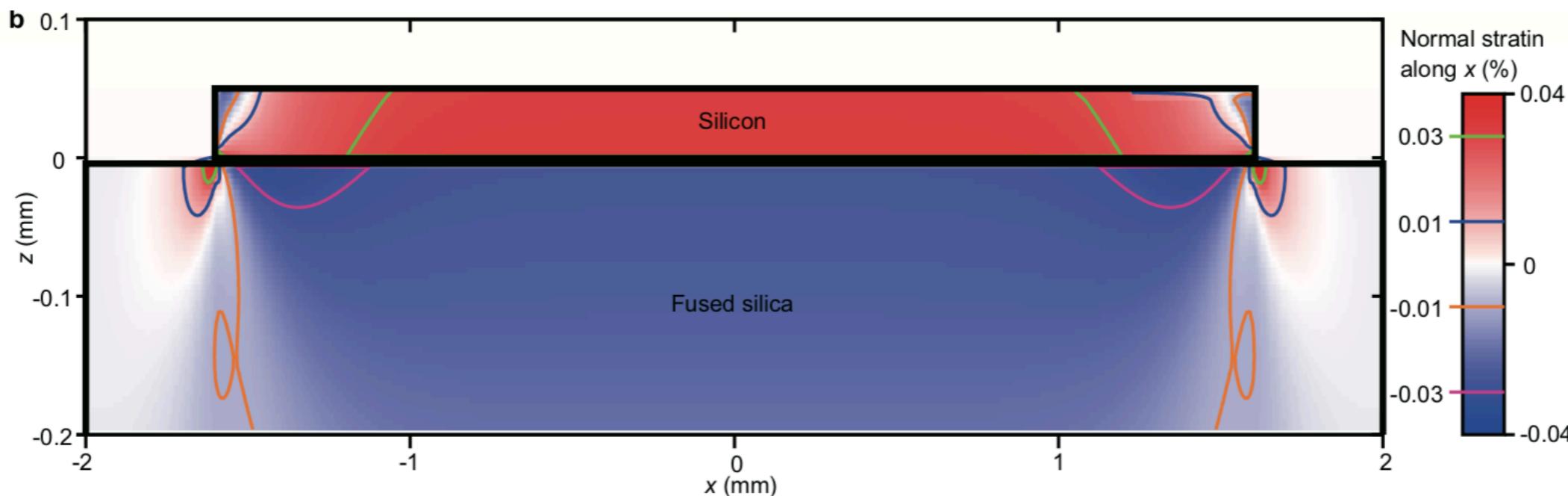
Kobayashi, **Salfi** et al, arxiv:1809.10859

Hole spin coherence

Direct strain measurement by Cryo-XRD



Strain inhomogeneity simulation



Kobayashi, **Salfi** et al, arxiv:1809.10859



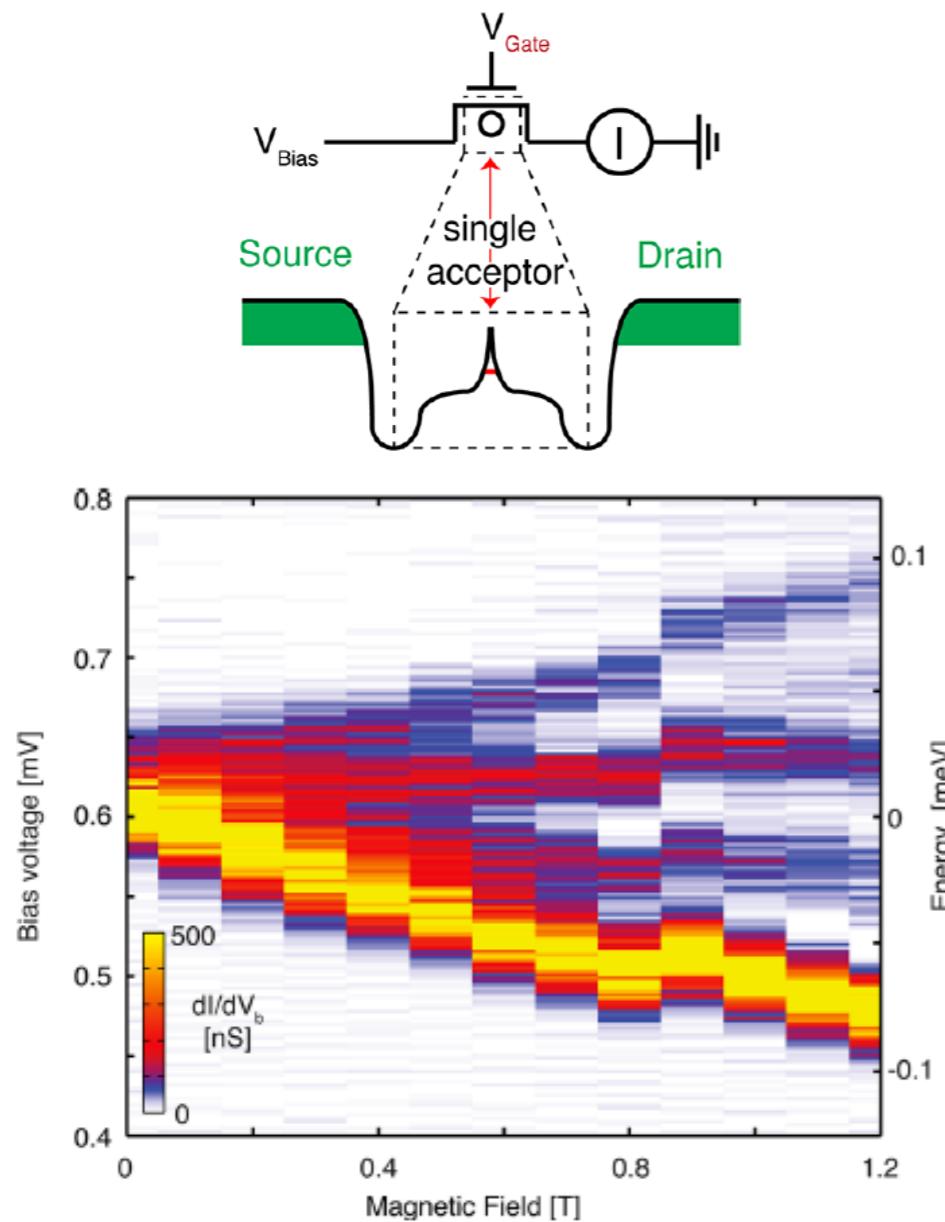
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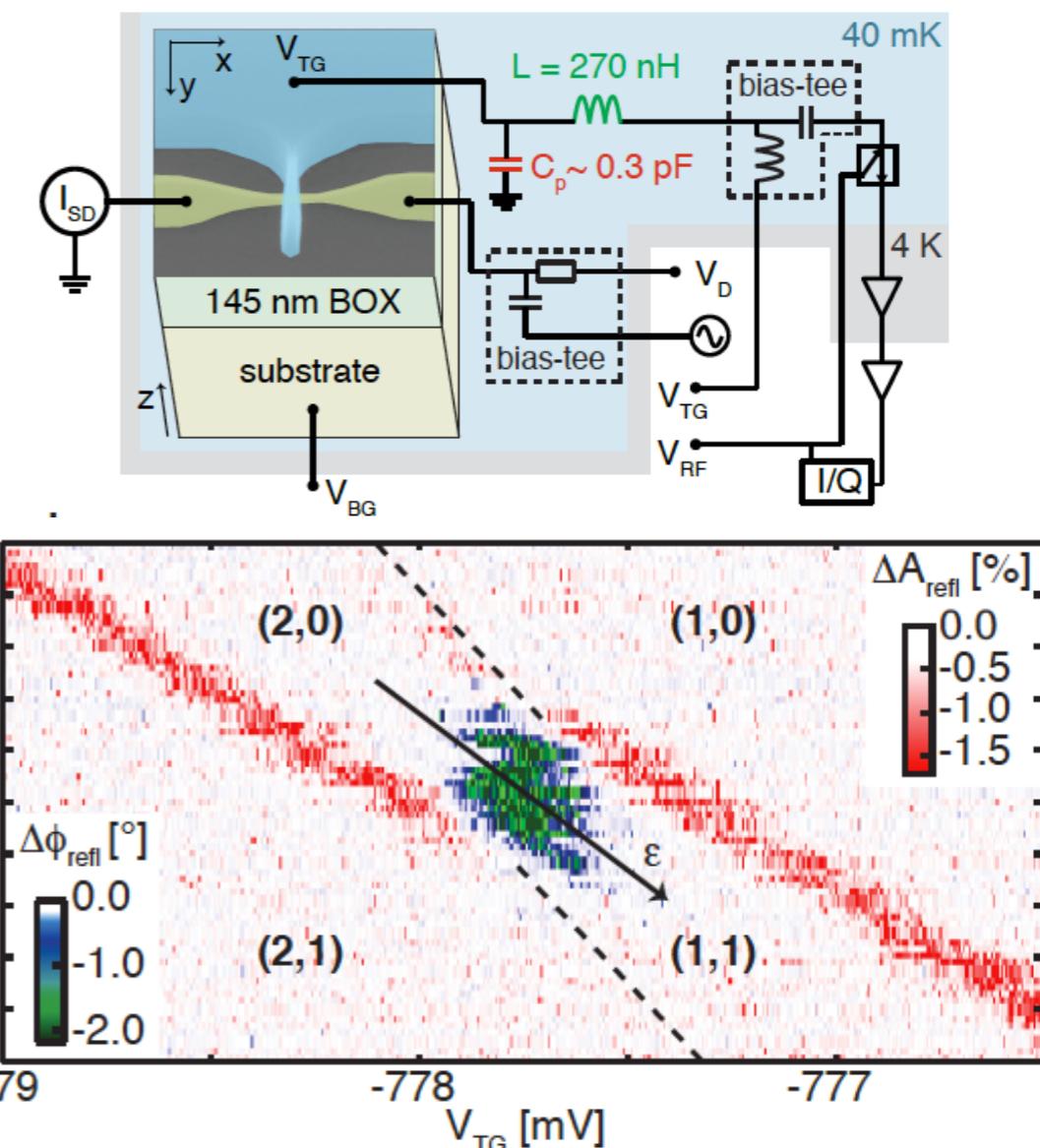
Si:B devices : single and coupled atoms

Single-atom transistor



van der Heijden et al, Nano Letters 2014

Gate-based spin readout

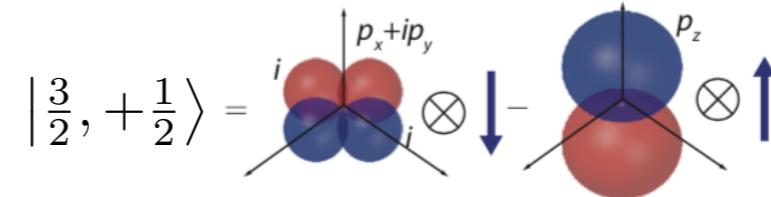
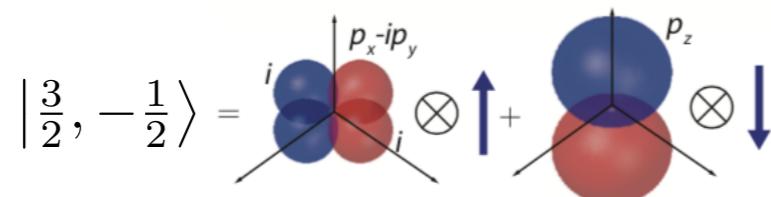


van der Heijden et al, Science Advances 2018

Summary

Summary of experiment: Holes in ^{28}Si

A $J=3/2$ system nearly as coherent as a $S=1/2$ (^{28}Si) or $S=1$ (Diamond)



Nontrivial: L.S coupling

10^4 to 10^5 coherence improvement over other spin-orbit systems

Strain increases T_1 by reducing spin-lattice coupling

Strain increases T_2 by reducing sensitivity to electric noise

Opportunities: long-range coupling, electric control + coherence

New experiments

CQED : deterministic gates, cavity optimized for atom qubits

Aim: 5 MHz spin-photon coupling, <1 kHz linewidth, sweet spot

Kobayashi, **Salfi** et al, arxiv:1809.10859

van der Heijden et al, Science Advances, 2018

Salfi et al, PRL 2016

Thank you!

@UNSW

Takashi Kobayashi
Cassandra Chua
Sven Rogge

Materials

H Riemann P Becker
N Abrosimov HJ Pohl

New Lab @ UBC (QMI)



Theory

Dimi Culcer (UNSW)
Bill Coish (hyperfine) (McGill)

B Johnson (Melbourne)
J McCallum (Melbourne)

Kobayashi, **Salfi** et al, arxiv:1809.10859
van der Heijden et al, Science Advances, 2018
Salfi et al, PRL 2016



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Thank you!

@UNSW

Takashi Kobayashi
Cassandra Chua
Sven Rogge

Materials

H Riemann P Becker
N Abrosimov HJ Pohl

Postdoctoral openings

1. Hybrid spin-3/2 devices”
2. “Quantum simulators”

Theory

Dimi Culcer (UNSW)
Bill Coish (hyperfine) (McGill)

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J McCallum (Melbourne)

Kobayashi, **Salfi** et al, arxiv:1809.10859
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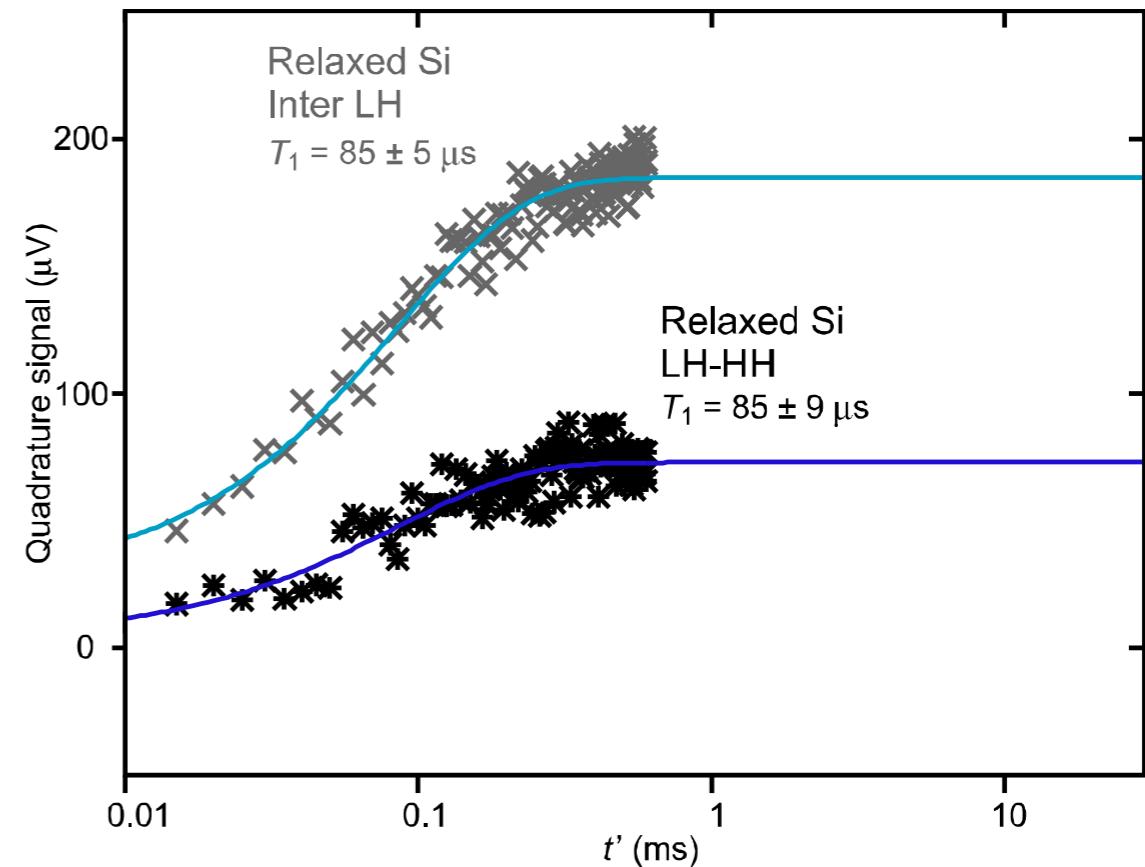
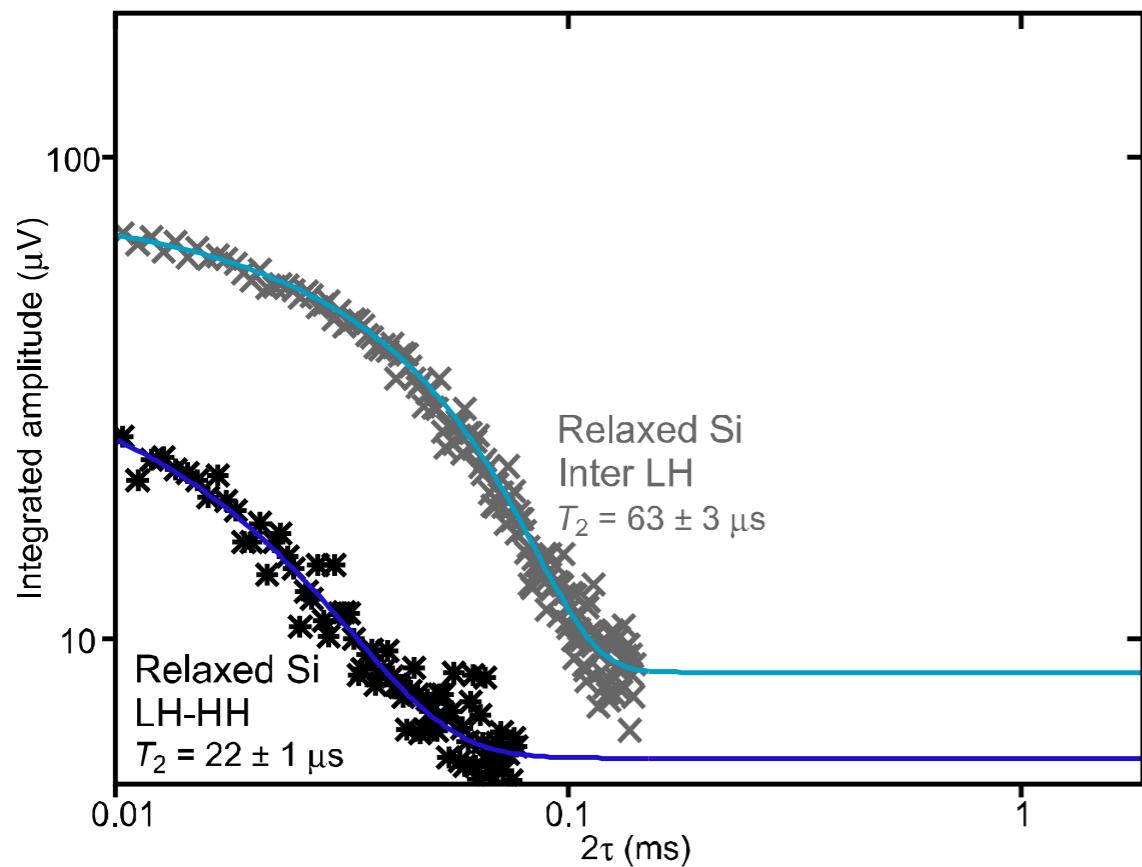
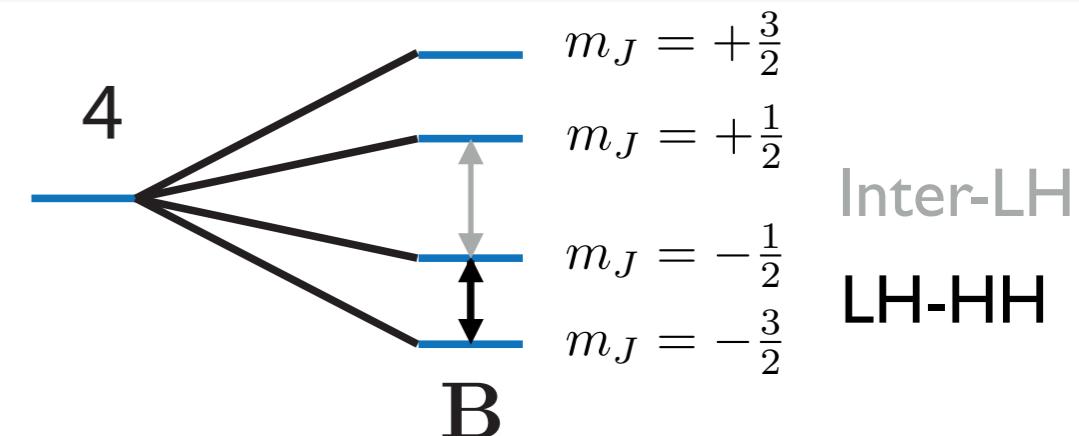
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Engineering hole spin coherence

The four-fold degenerate $J=3/2$ system

Inter-LH: $m_J = \pm 1/2$

LH-HH: $m_J = -3/2$ to $-1/2$



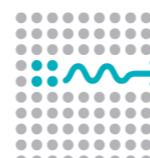
Comparison: same T_1 , better T_2 for time-reversed system

Kobayashi, **Salfi** et al, arxiv:1809.10859



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